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** CONTINUING DATA *****

This application is a DIV of 09/596,116 06/16/2000 PAT 6,436,526

** FOREIGN APPLICATIONS *****

JAPAN 11-170486 06/17/1999

JAPAN 11-352962 12/13/1999

IF REQUIRED, FOREIGN FILING LICENSE GRANTED

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35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged Examiner's Signature _____ Initials _____				

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TITLE

Magneto-resistance effect element magneto-resistance effect memory cell, MRAM, and method for performing information write to or read from the magneto-resistance effect memory cell

☐ All Fees

☐ 1.16 Fees (Filing)